Attorney Docket No: 740756-2351 Form PTO-1449 U.S. Department of Commerce Serial No. Not Yet Assigned (Rev. 8-83) Patent and Trademark Office INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary) Applicant: Shunpei YAMAZAKI et al. Filing Date: August 21, 2001 Group: 281 **U.S. PATENT DOCUMENTS** Examiner Document Number Date Name Class Subclass Filing Date Initial (if appropriate) 5,612,250 03/18/1997 Ohtani et al. 5,543,352 08/06/1996 Ohtani et al. 5,895,933 04/20/1999 Zhang et al. 5,882,960 03/16/1999 Zhang ct al. 6,051,453 04/18/2000 Takemura 5,953,597 09/14/1999 Kusumoto et al. 5,561,081 10/01/1996 Takenouchi et al. 5,897,799 04/27/1999 Yamazaki et al. 6,002,101 12/14/1999 Yamazaki et al. 5,968,383 10/19/1999 Yamazaki et al. 5,900,980 05/04/1999 Yamazaki et al. 6,038,075 03/14/2000 Yamazaki et al. 5,959,779 09/28/1999 Yamazaki et al. 6,002,523 12/14/1999 Tanaka FOREIGN PATENT DOCUMENTS Document Number Date Country Class Subclass Translation Yes 07-161634 06/23/1995 Japan Abstract 07-321339 12/08/1995 Japan Abstract 07-131034 05/19/1995 Japan Abstract OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.) Specification and Drawings for Patent Application Serial No. 09/610,637, "Laser Irradiation Apparatus, Laser Irradiation Method, Semiconductor Device, and Method of Manufacturing a Semiconductor Device". Examiner Date Considered \*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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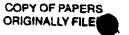
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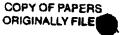
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Form PTO-1449 **U.S.Department of Commerce** Atty Docket 0756-2351 Serial No. 09/932,935 (Rev. 8-83) Patent and Trademark Office Applicants: Shunpei YAMAZAKI et al. INFORMATION DISCLOSURE STATEMENT Filing Date: August 21, 2001 Group Art Unit: 2812 U.S. PATENT DOCUMENTS Filing Date (If appropriate) Examir **Decument Number** Date Name Class Subclass initial 4,609,407 09/02/1986 A THADE Masao et al. 5,432,122 07/11/1995 Chae 03/18/1997 5,612,251 66 5,643,801 07/01/1997 Ishihara et al. 5,972,742 10/26/1999 Zhang et al. Owa et al. 6,088,379 07/11/2000 FOREIGN PATENT DOCUMENTS Translation Yes No **Document Number** Examine Date Country Class Subclass 10/03/1997 Eng Abst 09-260676 JP 06/01/1981 56-064480 Eng Abst **OTHER DOCUMENT** (Including Author, Title, Date, Pertinent Pages, Etc.) Examiner Initial Helen et al., "Reproducible High Field Effect Mobility Polysilicon Thin Film Transistors Involving Pulsed Nd: YVO4 Laser Crystallization", pp. 297-300, 1999, IEDM 0-7803-5410-9/99 IEEE 774,637 Date Considered \*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this formwith next communication to applicant.

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